Patent Claims

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5	1.	A sensor device (10; 30; 50; 70; 80; 90; 120; 140; 150; 170; 190; 200
	300;	100; 500) having

- a first capacitor (C2), which comprises a first electrically conductive area (12.1; 32.1; 52; 72; 82.1; 142.n; 152.1, 152.2, 152.n; 172; 192), a second electrically conductive area (11; 31; 53; 73; 83; 143; 153.1, 153.2, 153.n; 173), and a dielectric layer (13; 33; 124; 174),
- a conductive absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503), which has a conductive connection to the first area (12.1; 32.1; 52; 72; 82.1; 142.n; 152.1, 152.2, 152.n; 172; 192) of the first capacitor (C2),
- in AC voltage generator (G), for coupling an AC voltage signal (s1(t)) into the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503),
- a sensor amplifier (A) for amplifying an output signal (s2(t)), which may be tapped at the second area (11; 31; 53; 73; 83; 143; 153.1, 153.2, 153.n; 173) of the first capacitor (C2), wherein the sensor device (10; 30; 50; 70; 80; 90; 120; 140; 150; 170; 190; 200; 300; 400; 500) is designed in such a way that
- the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503) forms an additional capacitor (C3), whose effective capacitance is changeable, when an object (18; 38; 148) approaches, and
- the output signal (s2(t)) experiences damping, which is detectable, due to this effective capacitance.

- The sensor device (10; 30; 50; 70; 80; 90; 120; 140; 150; 170; 190; 200; 300; 400; 500) according to Claim 1, characterized in that the first capacitor (C2) is positioned in relation to the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503) in such a way that a leakage field of the first capacitor (C2) may only be influenced insignificantly by the object (18; 38; 148), the first capacitor (C2) preferably being positioned behind a side of the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503), which faces away from the first side of the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503).
- The sensor device (30; 50; 70; 80; 90; 120; 140; 150; 170; 190; 200; 300; 400; 500) according to Claim 1 or 2, having a second capacitor (C1), which comprises a first electrically conductive area (32.3; 52; 72; 82.1; 142.1; 152.1, 152.2, 152.n; 172; 192), a second electrically conductive area (41; 51; 71; 81; 141; 151.1, 151.2, 151.n; 183), and a dielectric layer (43; 174; 194), wherein the first area (32.3; 52; 72; 82.1; 142.1; 152.1, 152.2, 152.n; 172; 192) of the second capacitor (C1) has an electrically conductive connection to the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503), and the second area (41; 51; 71; 81; 141; 151.1, 151.2, 151.n; 183) of the second capacitor (C1) is electrically connected to the AC voltage generator (G).
- The sensor device (30; 50; 70; 80; 90; 120; 140; 150; 170; 190; 200;
 300; 400; 500) according to Claim 3,
 wherein the AC voltage signal (s1(t)) is coupled in via the second capacitor (C1).
- The sensor device (30; 50; 70; 80; 90; 120; 140; 150; 170; 190; 200;
 300; 400; 500) according to Claim 3 or 4,
 wherein the second capacitor (C1) is preferably positioned behind a side of the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n;
 152.1, 152.2, 152.n; 172; 192; 301; 402; 503) which faces away from the first

side of the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503).

- The sensor device (10; 30; 50; 70; 80; 90; 120; 140; 150; 170; 190;
 200; 300; 400; 500) according to one of the preceding claims, characterized in that the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503) has an arbitrary two-dimensional or three-dimensional shape.
- The sensor device (10; 30; 50; 70; 80; 90; 120; 140; 150; 170; 190; 200; 300; 400; 500) according to one of the preceding claims, characterized in that the absorption area (12.2; 32.2; 52; 72; 82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n; 172; 192; 301; 402; 503) is laid out so that its shape and/or size is changeable, the change preferably occurring in a step before mounting of the sensor device.
- The sensor device (10; 30; 50; 70; 80; 90; 120; 140; 150; 170; 190; 200; 300; 400; 500) according to one of the preceding claims, characterized in that an insulation layer (14, 15; 34, 35; 194, 195; 401; 501) is positioned on a first side of the absorption area (12.2; 32.2; 52; 62; 72; 82.1, 82.2, 82.3; 142.2; 152.1, 152.2, 152.n; 172; 192; 402; 503).
 - 9. The sensor device (80; 140; 150) according to one of the preceding claims,
- characterized in that the absorption area is divided into two or more partial areas (82.1, 82.2, 82.3; 142.1; 142.2; 142.n; 152.1, 152.2, 152.n), the partial areas either having a conductive connection to one another or a spacing (dL) being provided between the partial areas.
- 30 10. The sensor device (90) according to one of the preceding claims, characterized in that a shielding area (112) is provided, which preferably may be connected to ground or mass.

- 11. The sensor device (90) according to Claim 10, characterized in that the shielding area (112) is decoupled from the absorption area (32) by capacitors (41, 113, 112; 31, 104, 112).
- 5 12. The sensor device (120) according to one of Claims 1 through 9, characterized in that a further absorption area (122) and two further capacitors (C1', C2') are provided, the entire construction of the sensor device (120) preferably being symmetrical to a central plane.
- 10 13. The sensor device (10; 30; 90; 120; 140; 150) according to one of the preceding claims,

characterized in that

- n absorption areas (152.1, 152.2, 152.n) are positioned distributed in a plane or in space,
- the AC voltage signal (s1(t)) may be coupled into each of the n absorption areas (152.1, 152.2, 152.n),
 - n sensor amplifiers (160.1, 160.2, 160.n) are provided, and
 - an output stage (161.1, 161.2, 161.n) is provided behind each of the n sensor amplifiers (160.1, 160.2, 160.n),
- 20 n being a whole number greater than 1.
 - 14. The sensor device (10; 30; 90; 120; 140; 150) according to one of Claims 1 through 12,

characterized in that one or more of the following elements is connected downstream from the sensor amplifier (20; 40; 100; 130; 160.1, 160.1, 160.n):

- a filter (201),
- an AC/DC converter (202),
- an analog/digital converter (161.1, 161.2, 161.n),
- a microprocessor (162; 204) or computer.

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15. The sensor device (10; 30; 90; 120; 140; 150) according to one of Claims 1 through 12, characterized in that an attenuated AC voltage signal (s1(t)) is coupled into a flu-

id medium, the output signal (s2(t)) experiencing an amplification which may be

5 differentiated from the damping.

- 16. An installation having a sensor device (10; 30; 50; 70; 80; 90; 120; 140; 150; 170; 190; 200; 300; 400; 500) according to one of Claims 1 through 15.
- 10 17. The installation according to Claim 16, characterized in that it is a sanitary installation, building installation, kitchen installation, door installation, security installation, or elevator installation.
- 18. The installation according to Claim 16,15 characterized in that it is an installation (500) for level measurement or leak recognition.
 - 19. The installation according to Claim 16, characterized in that it is an installation (400) for detecting a urine stream.
 - 20. The installation according to Claim 16, characterized in that a water supply tap (301) is used as the absorption area.

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